INSTITUTE OF HIGH ENERGY PHYSICS 182

# Nb Sample analysis at IHEP

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### **Experiment assignment**

- To analyze the concentration of elements in different niobium samples, we use time-of-flight secondary ion mass spectrometry (TOF-SIMS) to measure them.
- After TOF-SIMS measurement, we use scanning electron microscope (SEM) to see the surface image of Nb samples. For the light N-doping sample, and the nitride precipitates is clear as shown below.



- The resistance versus temperature of fine grain and large grain samples is measured by physical property measurement system (PPMS).
- □ We use MPMS to measure the DC/AC magnetic performance of Nb/Nb(doped)/SIS samples.



### **TOF - SIMS Results of N-doping at OTIC**



#### Furnace at Ningxia Orient Tantalum Industry Co., Ltd (OTIC)



**Before N-doping** 







### **Resistance vs Temperature (RT)**

The RT curve is measured from room temperature down to 5K, using a fourpoint probe method by PPMS.







### **The DC Magnetic Measurement: MT**

Magnetic field intensity is 50Oe and it is perpendicular to the surface of sample. Temperature: from 16K to 2K.

When exposed to a static magnetic field, the superconducting sample will exhibit a negative magnetic moment. The Tc values are similar with RT results, the diamagnetism is different for LG/FG. More inpurities in polycrystal will cause flux pinning, then influence the magnetic





### **The DC Magnetic Measurement: MH**

The magnetic moment is measured by increasing magnetic field from 0 to 3000 Oe, and the test temperature is 6K.

Because the sample is not in ideal geometry, the first point deviated from the linear dependence can not be considered as H<sub>c1</sub>.

Thus, we define this point the first detected flux entry into the sample as H<sub>entry</sub>.





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### **The DC Magnetic Measurement of SS/SIS structure**

#### 谭腾等. 低温物理学报 31, 179 (2009)



 $MgB_2/Nb$ : the  $MgB_2$  thin film turns diamagnetic at about 38.6K, indicating the superconductivity happens at the same temperature. The sharp transition at 10.56K results from the screening effect of Nb substrate.

DC (Yes!)



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## The AC Magnetic Measurement of SS/SIS structure



When superconducting sample under the AC magnetic field H, the phase of magnetic induction intensity B will delay due to damping. The AC magnetic susceptibility can be expressed as follows,

$$\chi = \frac{B}{\mu_0 H} - 1 = \frac{B_m}{\mu_0 H_m} e^{-i\delta} - 1 = \chi' + i\chi''$$

The real part of AC susceptibility has a transition, while the imaginary part shows a peak as the resistivity changes. In contrast with the DC mode, the AC magnetization is more sensitive to the superconducting transition.





### Next to do

(1) EP facility is under development, which will be completed in late 2018, and a new furnace will be shipped to IHEP in middle 2018, so our N-doping/infusion technology will be improved.

(2) Research the electromagnetic properties of N-doping/infusion samples taking demagnetization factor into consideration.

(3) Explore the properties of some new structures, such as SS/SIS.....

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